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First Named Inventor: Richard A. Blanchard
Group Art Unit: Unknown
Examiner Name: Unknown
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

U.S. Patent Documents

Examiner Initials	Cite No.	U.S.Patent Number	Kind Code	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YY	Pages, Columns, Lines Where Relevant Passages or Figures Appear
		6,462,396		Lemaire	8-8-02	
		6,233,012		Guerrieri et al.	5-15-01	

Foreign Patent Documents

Examiner Initials	Cite No.	Office	Number	Kind Code	Name of Patentee or Applicant	Date of Publication MM-DD-YY	Location of Relevant Passages/Figures	T

Other Prior Art - Non Patent Literature Documents

Examiner Initials	Cite No	Name of Author (All Caps), Title of Article/Item, Date, Page(s), Volume-Issue Number(s), Publisher, City and/or Country Where Published	T
		WU, YI-CHENG ET AL., On-Chip RF Sprial Inductors and Bandpass Filters Using Active Magnetic Energy Recovery, Proceedings of the IEEE 2002 Custom Integrated Circuits Conference, June 2002.	
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Examiner Signature		Date Considered	

**EXAMINER: Initial citation considered. Draw line through citation if no in conformance and not considered. Include copy of this form with next communication to application.